

LM7121 235-MHz Tiny Low Power Voltage Feedback Amplifier

1 Features

- (Typical Unless Otherwise Noted). $V_S = \pm 15\text{ V}$
- Easy to use Voltage Feedback Topology
- Stable with Unlimited Capacitive Loads
- Tiny SOT23-5 Package — Typical Circuit Layout Takes Half the Space Of SO-8 Designs
- Unity Gain Frequency: 175 MHz
- Bandwidth (-3 dB , $A_V = +1$, $R_L = 100\Omega$): 235 MHz
- Slew Rate: 1300V/ μs
- Supply Voltages:
 - SO-8: 5 V to $\pm 15\text{ V}$
 - SOT23-5: 5 V to $\pm 5\text{ V}$
- Characterized for: +5 V, $\pm 5\text{ V}$, $\pm 15\text{ V}$
- Low Supply Current: 5.3 mA

2 Applications

- Scanners, Color Fax, Digital Copiers
- PC Video Cards
- Cable Drivers
- Digital Cameras
- ADC/DAC Buffers
- Set-top Boxes

3 Description

The LM7121 is a high performance operational amplifier which addresses the increasing AC performance needs of video and imaging applications, and the size and power constraints of portable applications.

The LM7121 can operate over a wide dynamic range of supply voltages, from 5 V (single supply) up to $\pm 15\text{ V}$ (see [Application and Implementation](#) for more details). It offers an excellent speed-power product delivering 1300 V/ μs and 235 MHz Bandwidth (-3 dB , $A_V = +1$). Another key feature of this operational amplifier is stability while driving unlimited capacitive loads.

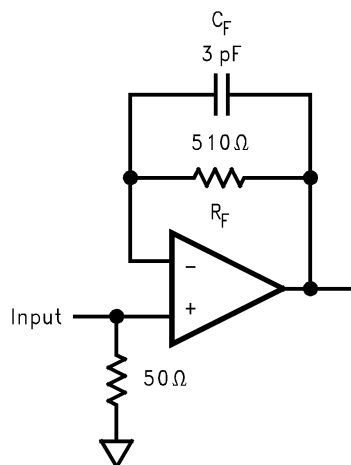
Due to its tiny SOT23-5 package, the LM7121 is ideal for designs where space and weight are the critical parameters. The benefits of the tiny package are evident in small portable electronic devices, such as cameras, and PC video cards. Tiny amplifiers are so small that they can be placed anywhere on a board close to the signal source or near the input to an A/D converter.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
LM7121	SOT-23 (5)	2.921 mm x 1.651 mm
	SOIC (8)	4.902 mm x 3.912 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Typical Circuit for $A_V = +1$ Operation
($V_S = 6\text{ V}$)



Unity Gain Frequency vs. Supply Voltage

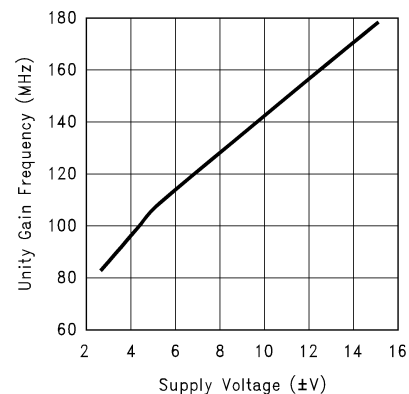


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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (August 1999) to Revision A	Page
• Added, updated, or renamed the following sections: Device Information Table, <i>Pin Configuration and Functions</i> , <i>Application and Implementation</i> ; <i>Power Supply Recommendations</i> ; <i>Layout</i> ; <i>Device and Documentation Support</i> ; <i>Mechanical, Packaging, and Ordering Information</i>	1
• Deleted $T_J = 25^\circ\text{C}$ from Electrical Characteristics tables	5

5 Pin Configuration and Functions



Pin Functions

NAME	PIN		I/O	DESCRIPTION
	NUMBER			
	DBV	D0008A		
-IN	4	2	I	Inverting input
+IN	3	3	I	Non-inverting input
N/C	—	5, 8	—	No connection
OUTPUT	1	6	O	Output
V ⁻	2	4	I	Negative supply
V ⁺	5	7	I	Positive supply

6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

	MIN	MAX	UNIT
Differential Input Voltage ⁽²⁾		±2	V
Voltage at Input/Output Pins		(V+)–1.4, (V–)+1.4	V
Supply Voltage (V+–V–)		36	V
Output Short Circuit to Ground ⁽³⁾		Continuous	
Lead Temperature (soldering, 10 sec)		260	°C
Junction Temperature ⁽⁴⁾		150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C.
- (3) The maximum power dissipation is a function of $T_{J(max)}$, $R_{\theta JA}$, and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(max)} - T_A) / R_{\theta JA}$. All numbers apply for packages soldered directly into a PC board.
- (4) Typical Values represent the most likely parametric norm.

6.2 Handling Ratings

	MIN	MAX	UNIT
T_{stg} Storage temperature range	–65	+150	°C
$V_{(ESD)}$ Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾		2000 V

- (1) JEDEC document JEP155 states that 2000-V HBM allows safe manufacturing with a standard ESD control process. Human body model, 1.5 k in series with 100 pF.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM	MAX	UNIT
Operating Temperature Range	–40		85	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		D0008A (8)	DBV (5)	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	165	325	°C/W

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

6.5 ±15V DC Electrical Characteristics

Unless otherwise specified, all limits ensured for $V^+ = +15V$, $V^- = -15V$, $V_{CM} = V_O = 0V$ and $R_L > 1M\Omega$. **Boldface** limits apply at the temperature extremes.

PARAMETER		TEST CONDITIONS	TYP ⁽¹⁾	LM7121 LIMIT ⁽²⁾	UNIT
V_{OS}	Input Offset Voltage		0.9	8 15	mV max
I_B	Input Bias Current		5.2	9.5 12	μA max
I_{OS}	Input Offset Current		0.04	4.3 7	μA max
R_{IN}	Input Resistance	Common Mode	10		$M\Omega$
		Differential Mode	3.4		$M\Omega$
C_{IN}	Input Capacitance	Common Mode	2.3		pF
CMRR	Common Mode Rejection Ratio	$-10V \leq V_{CM} \leq 10V$	93	73 70	dB min
+PSRR	Positive Power Supply Rejection Ratio	$10V \leq V^+ \leq 15V$	86	70 68	dB min
-PSRR	Negative Power Supply Rejection Ratio	$-15V \leq V^- \leq -10V$	81	68 65	dB min
V_{CM}	Input Common-Mode Voltage Range	CMRR ≥ 70 dB	13	11	V min
			-13	-11	V max
A_V	Large Signal Voltage Gain	$R_L = 2k\Omega$, $V_O = 20V_{PP}$	72	65 57	dB min
V_O	Output Swing	$R_L = 2k\Omega$	13.4	11.1 10.8	V min
			-13.4	-11.2 -11.0	V max
		$R_L = 150\Omega$	10.2	7.75 7.0	V min
			-7.0	-5.0 -4.8	V max
I_{SC}	Output Short Circuit Current	Sourcing	71	54 44	mA min
		Sinking	52	39 34	mA min
I_S	Supply Current		5.3	6.6 7.5	mA max

(1) Typical Values represent the most likely parametric norm.

(2) All limits are ensured by testing or statistical analysis.

6.6 ±15V AC Electrical Characteristics

Unless otherwise specified, all limits ensured for $V_+ = 15V$, $V_- = -15V$, $V_{CM} = V_O = 0V$ and $R_L > 1M\Omega$. **Boldface** limits apply at the temperature extremes.

PARAMETER		TEST CONDITIONS	TYP ⁽¹⁾	LM7121 LIMIT ⁽²⁾	UNIT
SR	Slew Rate ⁽³⁾	$A_V = +2$, $R_L = 1k\Omega$, $V_O = 20V_{PP}$	1300		V/ μ s
GBW	Unity Gain-Bandwidth	$R_L = 1k\Omega$	175		MHz
ϕ_m	Phase Margin		63		Deg
f (-3 dB)	Bandwidth ⁽⁴⁾⁽⁵⁾	$R_L = 100\Omega$, $A_V = +1$	235		MHz
		$R_L = 100\Omega$, $A_V = +2$	50		
t_s	Settling Time	10 V_{PP} Step, to 0.1%, $R_L = 500\Omega$	74		ns
t_r , t_f	Rise and Fall Time ⁽⁵⁾	$A_V = +2$, $R_L = 100\Omega$, $V_O = 0.4V_{PP}$	5.3		ns
A_D	Differential Gain	$A_V = +2$, $R_L = 150\Omega$	0.3%		
ϕ_D	Differential Phase	$A_V = +2$, $R_L = 150\Omega$	0.65		Deg
e_n	Input-Referred Voltage Noise	f = 10 kHz	17		nV / \sqrt{Hz}
i_n	Input-Referred Current Noise	f = 10 kHz	1.9		pA / \sqrt{Hz}
T.H.D.	Total Harmonic Distortion	2 V_{PP} Output, $R_L = 150\Omega$, $A_V = +2$, f = 1 MHz	0.065%		
		2 V_{PP} Output, $R_L = 150\Omega$, $A_V = +2$, f = 5 MHz	0.52%		

- (1) Typical Values represent the most likely parametric norm.
- (2) All limits are ensured by testing or statistical analysis.
- (3) Slew rate is the average of the rising and falling slew rates.
- (4) Unity gain operation for $\pm 5V$ and $\pm 15V$ supplies is with a feedback network of 510 Ω and 3 pF in parallel (see [Application and Implementation](#)). For +5V single supply operation, feedback is a direct short from the output to the inverting input.
- (5) $A_V = +2$ operation with 2 k Ω resistors and 2 pF capacitor from summing node to ground.

6.7 ±5V DC Electrical Characteristics

Unless otherwise specified, all limits ensured for $V_+ = 5V$, $V_- = -5V$, $V_{CM} = V_O = 0V$ and $R_L > 1M\Omega$. **Boldface** limits apply at the temperature extremes.

PARAMETER		TEST CONDITIONS	TYP ⁽¹⁾	LM7121 LIMIT ⁽²⁾	UNIT
V_{OS}	Input Offset Voltage		1.6	8 15	mV max
I_B	Input Bias Current		5.5	9.5 12	μ A max
I_{OS}	Input Offset Current		0.07	4.3 7.0	μ A max
R_{IN}	Input Resistance	Common Mode	6.8		M Ω
		Differential Mode	3.4		M Ω
C_{IN}	Input Capacitance	Common Mode	2.3		pF
CMRR	Common Mode Rejection Ratio	$-2V \leq V_{CM} \leq 2V$	75	65 60	dB min
+PSRR	Positive Power Supply Rejection Ratio	$3V \leq V^+ \leq 5V$	89	65 60	dB min
-PSRR	Negative Power Supply Rejection Ratio	$-5V \leq V^- \leq -3V$	78	65 60	dB min

- (1) Typical Values represent the most likely parametric norm.
- (2) All limits are ensured by testing or statistical analysis.

±5V DC Electrical Characteristics (continued)

Unless otherwise specified, all limits ensured for $V^+ = 5V$, $V^- = -5V$, $V_{CM} = V_O = 0V$ and $R_L > 1M\Omega$. **Boldface** limits apply at the temperature extremes.

PARAMETER		TEST CONDITIONS	TYP ⁽¹⁾	LM7121 LIMIT ⁽²⁾	UNIT
V_{CM}	Input Common Mode Voltage Range	CMRR ≥ 60 dB	3	2.5	V min
			-3	-2.5	V max
A_V	Large Signal Voltage Gain	$R_L = 2k\Omega$, $V_O = 3V_{PP}$	66	60 58	dB min
V_O	Output Swing	$R_L = 2k\Omega$	3.62	3.0 2.75	V min
			-3.62	-3.0 -2.70	V max
		$R_L = 150\Omega$	3.1	2.5 2.3	V min
			-2.8	-2.15 -2.00	V max
I_{SC}	Output Short Circuit Current	Sourcing	53	38 33	mA min
		Sinking	29	21 19	mA min
I_S	Supply Current		5.1	6.4 7.2	mA max

6.8 ±5V AC Electrical Characteristics

Unless otherwise specified, all limits ensured for $V^+ = 5V$, $V^- = -5V$, $V_{CM} = V_O = 0V$ and $R_L > 1M\Omega$. **Boldface** limits apply at the temperature extremes.

PARAMETER		TEST CONDITIONS	TYP ⁽¹⁾	LM7121 LIMIT ⁽²⁾	UNIT
SR	Slew Rate ⁽³⁾	$A_V = +2$, $R_L = 1k\Omega$, $V_O = 6V_{PP}$	520		V/ μ s
GBW	Unity Gain-Bandwidth	$R_L = 1k\Omega$	105		MHz
ϕ_m	Phase Margin	$R_L = 1k\Omega$	74		Deg
f (-3 dB)	Bandwidth ⁽⁴⁾⁽⁵⁾	$R_L = 100\Omega$, $A_V = +1$	160		MHz
		$R_L = 100\Omega$, $A_V = +2$	50		MHz
t_s	Settling Time	5 V_{PP} Step, to 0.1%, $R_L = 500\Omega$	65		ns
t_r , t_f	Rise and Fall Time ⁽⁵⁾	$A_V = +2$, $R_L = 100\Omega$, $V_O = 0.4V_{PP}$	5.8		ns
A_D	Differential Gain	$A_V = +2$, $R_L = 150\Omega$	0.3%		
ϕ_D	Differential Phase	$A_V = +2$, $R_L = 150\Omega$	0.65		Deg
e_n	Input-Referred Voltage Noise	f = 10 kHz	17		nV / \sqrt{Hz}
i_n	Input-Referred Current Noise	f = 10 kHz	2		pA / \sqrt{Hz}
T.H.D.	Total Harmonic Distortion	2 V_{PP} Output, $R_L = 150\Omega$, $A_V = +2$, f = 1 MHz	0.1%		
		2 V_{PP} Output, $R_L = 150\Omega$, $A_V = +2$, f = 5 MHz	0.6		

(1) Typical Values represent the most likely parametric norm.

(2) All limits are ensured by testing or statistical analysis.

(3) Slew rate is the average of the rising and falling slew rates.

(4) Unity gain operation for $\pm 5V$ and $\pm 15V$ supplies is with a feedback network of 510 Ω and 3 pF in parallel (see [Application and Implementation](#)). For +5V single supply operation, feedback is a direct short from the output to the inverting input.

(5) $A_V = +2$ operation with 2 k Ω resistors and 2 pF capacitor from summing node to ground.

6.9 +5V DC Electrical Characteristics

Unless otherwise specified, all limits ensured for $V^+ = +5V$, $V^- = 0V$, $V_{CM} = V_O = V^+/2$ and $R_L > 1\text{ M}\Omega$. **Boldface** limits apply at the temperature extremes.

PARAMETER	TEST CONDITIONS	TYP ⁽¹⁾	LM7121 LIMIT ⁽²⁾	UNIT
V_{OS}	Input Offset Voltage	2.4		mV
I_B	Input Bias Current	4		μA
I_{OS}	Input Offset Current	0.04		μA
R_{IN}	Input Resistance	Common Mode	2.6	M
		Differential Mode	3.4	M
C_{IN}	Input Capacitance	Common Mode	2.3	pF
CMRR	Common Mode Rejection Ratio	$2V \leq V_{CM} \leq 3V$	65	dB
+PSRR	Positive Power Supply Rejection Ratio	$4.6V \leq V^+ \leq 5V$	85	dB
-PSRR	Negative Power Supply Rejection Ratio	$0V \leq V^- \leq 0.4V$	61	dB
V_{CM}	Input Common-Mode Voltage Range	CMRR 45 dB	3.5	V min
			1.5	V max
A_V	Large Signal Voltage Gain	$R_L = 2\text{ k}\Omega$ to $V^+/2$	64	dB
V_O	Output Swing	$R_L = 2\text{ k}\Omega$ to $V^+/2$, High	3.7	V
		$R_L = 2\text{ k}\Omega$ to $V^+/2$, Low	1.3	
		$R_L = 150\ \Omega$ to $V^+/2$, High	3.48	
		$R_L = 150\ \Omega$ to $V^+/2$, Low	1.59	
I_{SC}	Output Short Circuit Current	Sourcing	33	mA
		Sinking	20	mA
I_S	Supply Current		4.8	mA

(1) Typical Values represent the most likely parametric norm.

(2) All limits are ensured by testing or statistical analysis.

6.10 +5V AC Electrical Characteristics

Unless otherwise specified, all limits ensured for $V^+ = +5V$, $V^- = 0V$, $V_{CM} = V_O = V^+/2$ and $R_L > 1\text{ M}\Omega$. **Boldface** limits apply at the temperature extremes.

PARAMETER	TEST CONDITIONS	TYP ⁽¹⁾	LM7121 LIMIT ⁽²⁾	UNIT
SR	Slew Rate ⁽³⁾	$A_V = +2$, $R_L = 1\text{ k}\Omega$ to $V^+/2$, $V_O = 1.8\text{ V}_{PP}$	145	V/ μs
GBW	Unity Gain-Bandwidth	$R_L = 1\text{ k}\Omega$ to $V^+/2$	80	MHz
ϕ_m	Phase Margin	$R_L = 1\text{ k}\Omega$ to $V^+/2$	70	Deg
f (-3 dB)	Bandwidth ⁽⁴⁾⁽⁵⁾	$R_L = 100\ \Omega$ to $V^+/2$, $A_V = +1$	200	MHz
		$R_L = 100\ \Omega$ to $V^+/2$, $A_V = +2$	45	
t_r , t_f	Rise and Fall Time ⁽⁵⁾	$A_V = +2$, $R_L = 100\ \Omega$, $V_O = 0.2\text{ V}_{PP}$	8	ns
T.H.D.	Total Harmonic Distortion	0.6 V_{PP} Output, $R_L = 150\ \Omega$, $A_V = +2$, $f = 1\text{ MHz}$	0.067%	
		0.6 V_{PP} Output, $R_L = 150\ \Omega$, $A_V = +2$, $f = 5\text{ MHz}$	0.33%	

(1) Typical Values represent the most likely parametric norm.

(2) All limits are ensured by testing or statistical analysis.

(3) Slew rate is the average of the rising and falling slew rates.

(4) Unity gain operation for $\pm 5\text{ V}$ and $\pm 15\text{ V}$ supplies is with a feedback network of $510\ \Omega$ and 3 pF in parallel (see [Application and Implementation](#)). For +5V single supply operation, feedback is a direct short from the output to the inverting input.

(5) $A_V = +2$ operation with $2\text{ k}\Omega$ resistors and 2 pF capacitor from summing node to ground.

6.11 Typical Characteristics

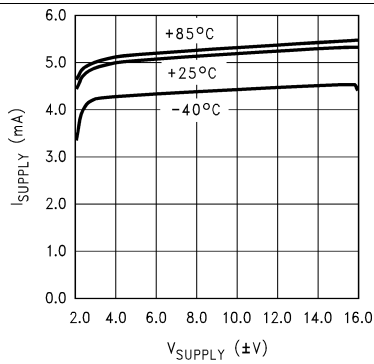


Figure 1. Supply Current vs. Supply Voltage

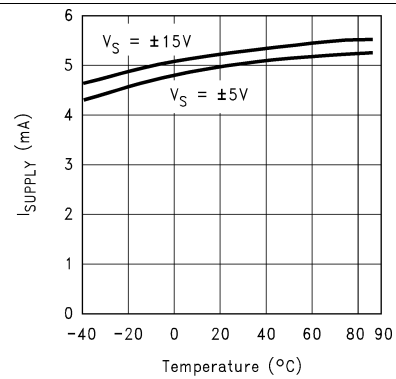


Figure 2. Supply Current vs. Temperature

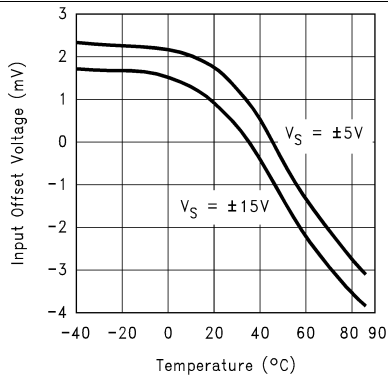


Figure 3. Input Offset Voltage vs. Temperature

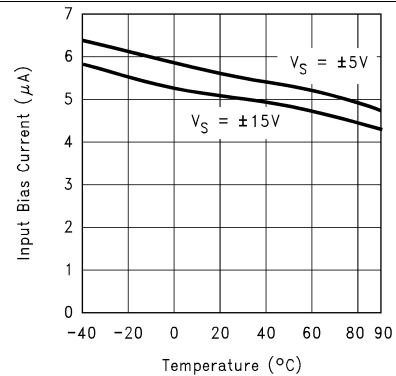


Figure 4. Input Bias Current vs. Temperature

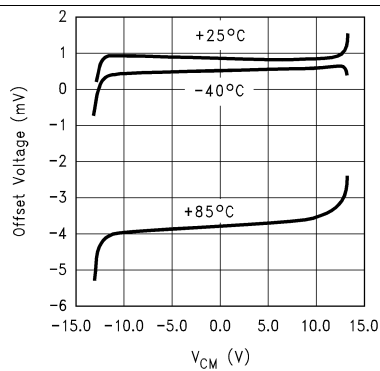


Figure 5. Input Offset Voltage vs. Common Mode Voltage at $V_S = \pm 15\text{ V}$

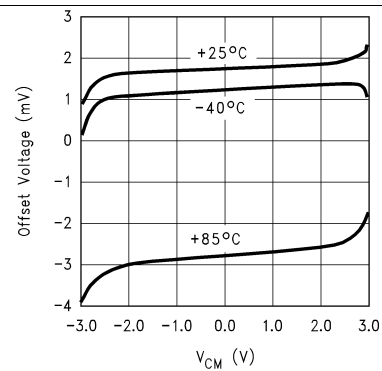


Figure 6. Input Offset Voltage vs. Common Mode Voltage at $V_S = \pm 5\text{ V}$

Typical Characteristics (continued)

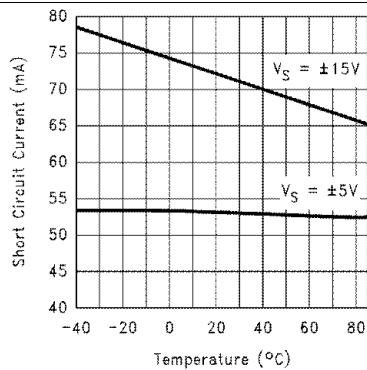


Figure 7. Short Circuit Current vs. Temperature (Sourcing)

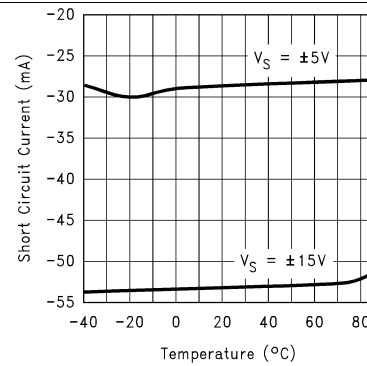


Figure 8. Short Circuit Current vs. Temperature (Sinking)

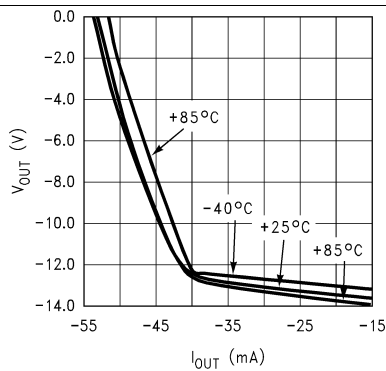


Figure 9. Output Voltage vs. Output Current (ISINK, VS = ±15 V)

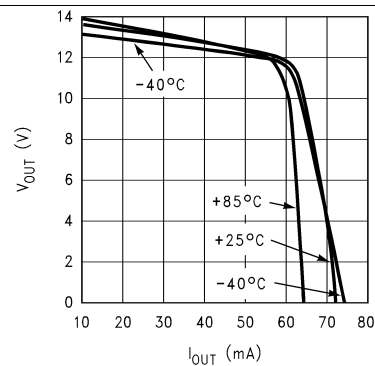


Figure 10. Output Voltage vs. Output Current (ISOURCE, VS = ±15 V)

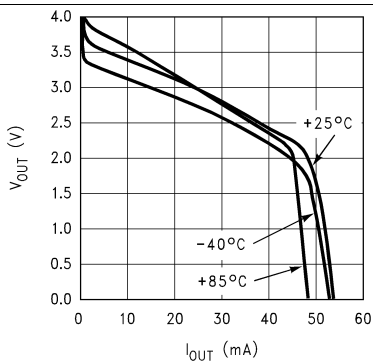


Figure 11. Output Voltage vs. Output Current (ISOURCE, VS = ±5 V)

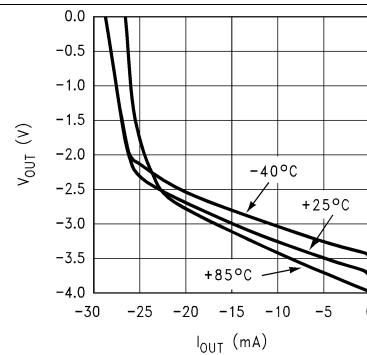


Figure 12. Output Voltage vs. Output Current (ISINK, VS = ±5 V)

Typical Characteristics (continued)

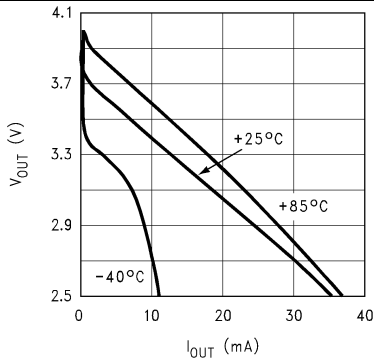


Figure 13. Output Voltage vs. Output Current (I_{SOURCE}, V_S = +5 V)

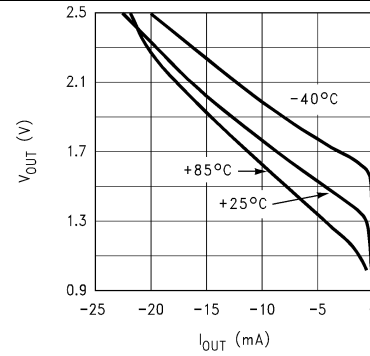


Figure 14. Output Voltage vs. Output Current (I_{SINK}, V_S = +5 V)

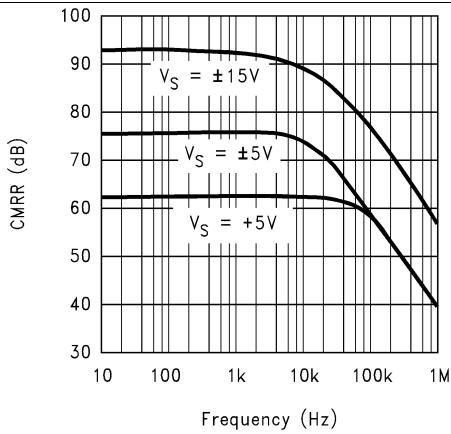


Figure 15. CMRR vs. Frequency

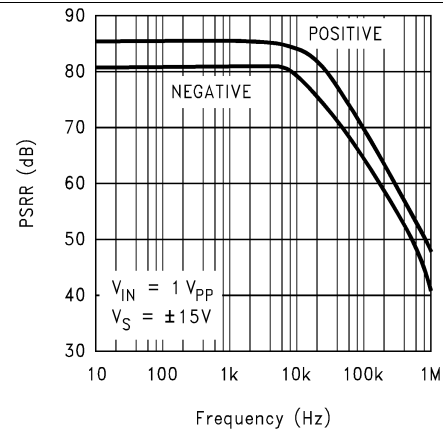


Figure 16. PSRR vs. Frequency

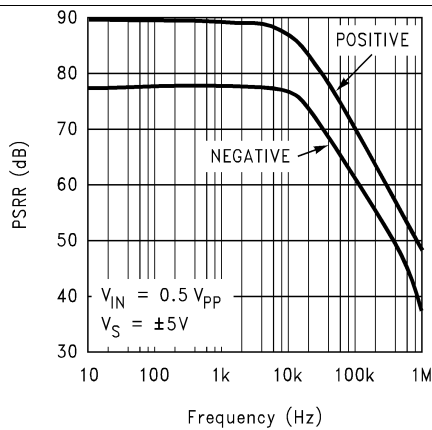


Figure 17. PSRR vs. Frequency

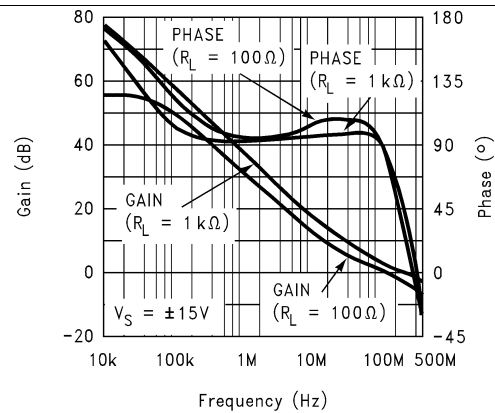


Figure 18. Open Loop Frequency Response

Typical Characteristics (continued)

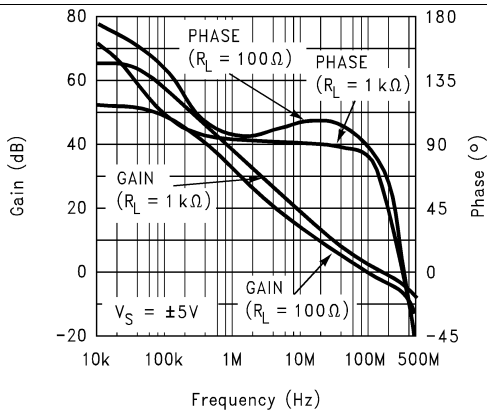


Figure 19. Open Loop Frequency Response

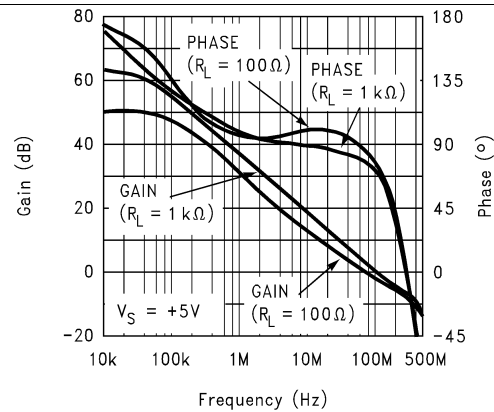


Figure 20. Open Loop Frequency Response

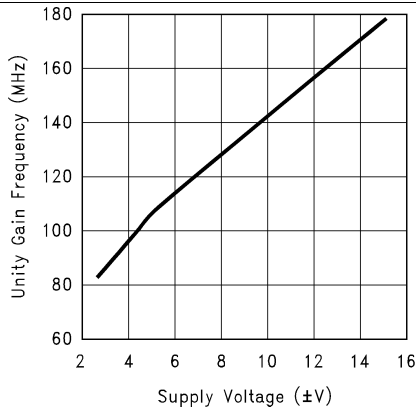


Figure 21. Unity Gain Frequency vs. Supply Voltage

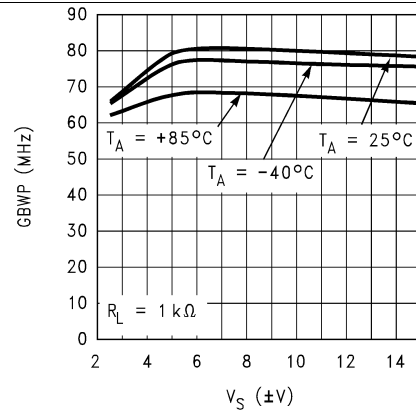


Figure 22. GBWP at 10 MHz vs. Supply Voltage

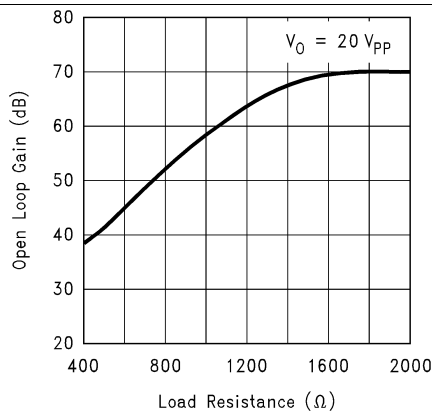


Figure 23. Large Signal Voltage Gain vs. Load, $V_S = \pm 15 V$

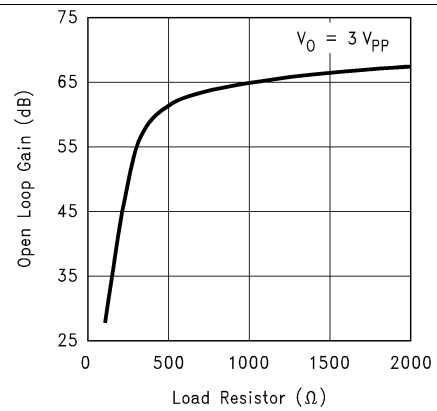


Figure 24. Large Signal Voltage Gain vs. Load, $V_S = \pm 5 V$

Typical Characteristics (continued)

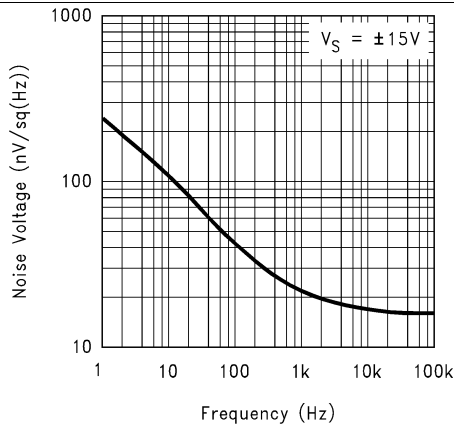


Figure 25. Input Voltage Noise vs. Frequency

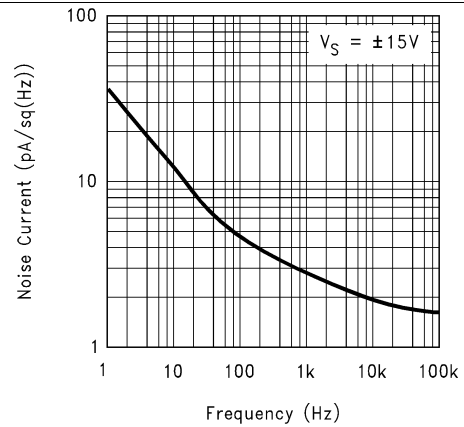


Figure 26. Input Current Noise vs. Frequency

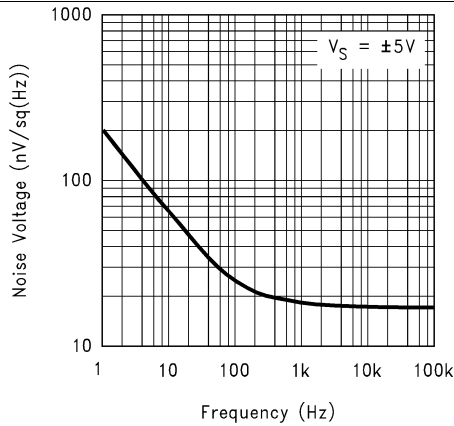


Figure 27. Input Voltage Noise vs. Frequency

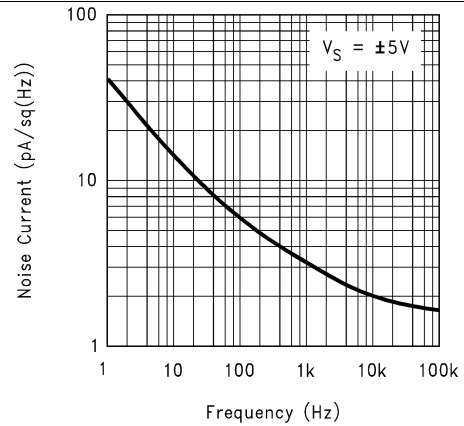


Figure 28. Input Current Noise vs. Frequency

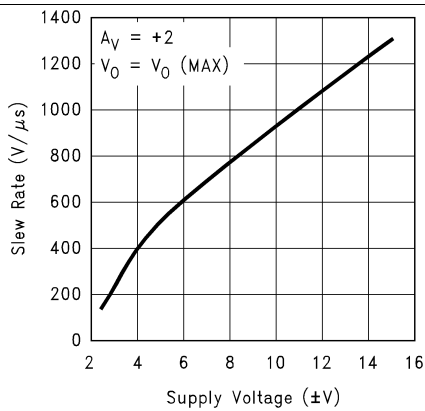


Figure 29. Slew Rate vs. Supply Voltage

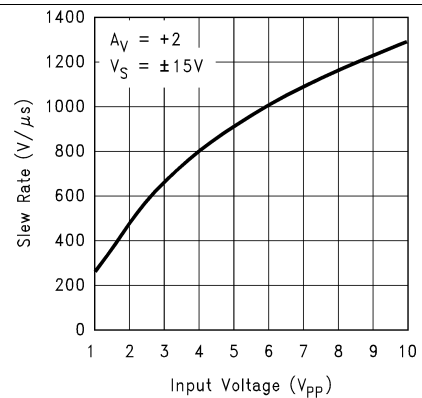


Figure 30. Slew Rate vs. Input Voltage

Typical Characteristics (continued)

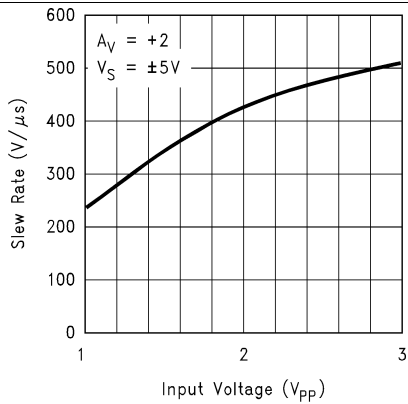


Figure 31. Slew Rate vs. Input Voltage

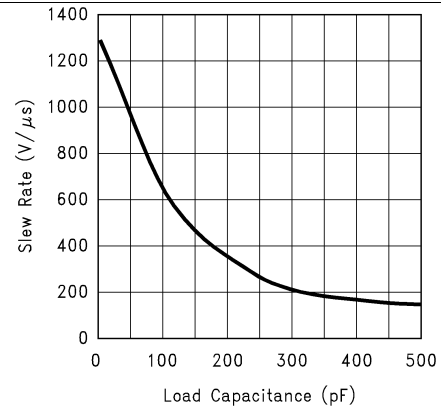


Figure 32. Slew Rate vs. Load Capacitance

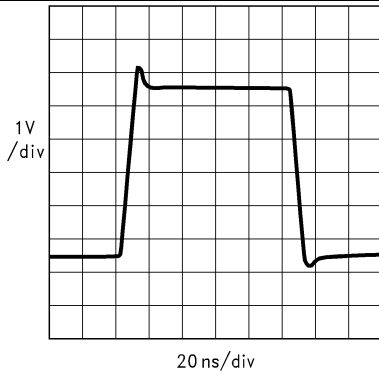


Figure 33. Large Signal Pulse Response, $A_V = -1$, $V_S = \pm 15$ V

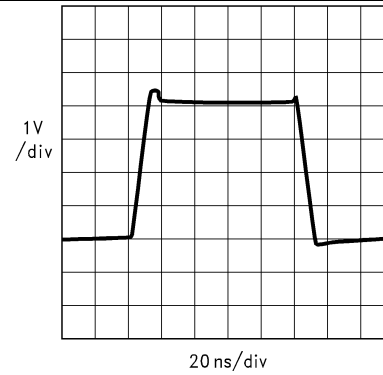


Figure 34. Large Signal Pulse Response, $A_V = -1$, $V_S = \pm 5$ V

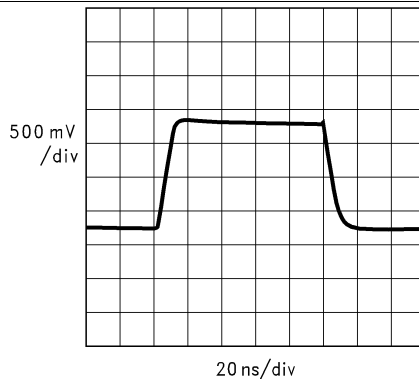


Figure 35. Large Signal Pulse Response, $A_V = -1$, $V_S = +5$ V

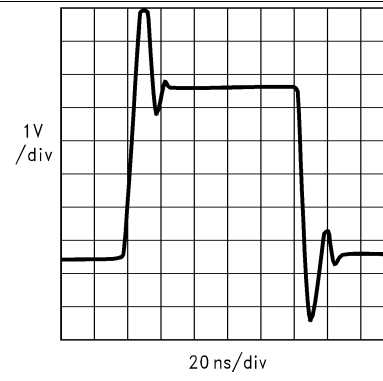


Figure 36. Large Signal Pulse Response, $A_V = +1$, $V_S = \pm 5$ V

Typical Characteristics (continued)

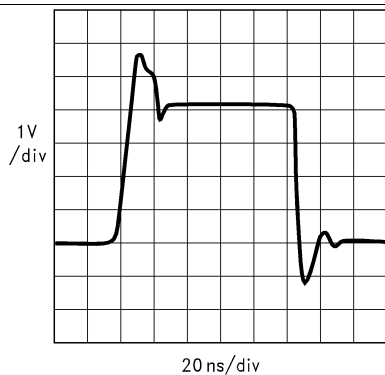


Figure 37. Large Signal Pulse Response,
 $A_V = +1$, $V_S = \pm 5$ V

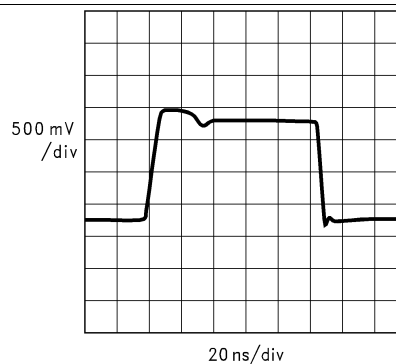


Figure 38. Large Signal Pulse Response,
 $A_V = +1$, $V_S = +5$ V

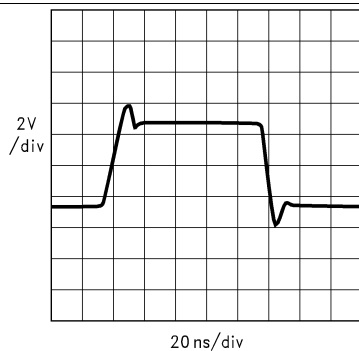


Figure 39. Large Signal Pulse Response,
 $A_V = +2$, $V_S = \pm 15$ V

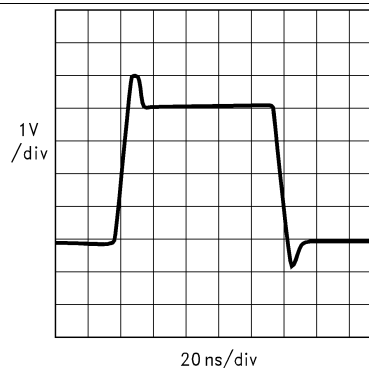


Figure 40. Large Signal Pulse Response,
 $A_V = +2$, $V_S = \pm 5$ V

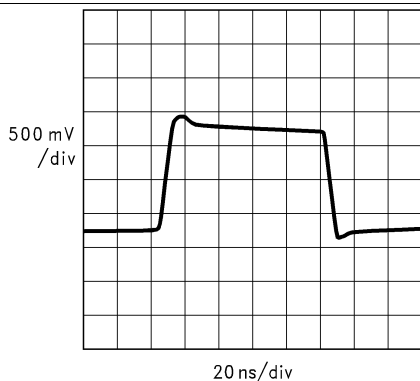


Figure 41. Large Signal Pulse Response,
 $A_V = +2$, $V_S = +5$ V

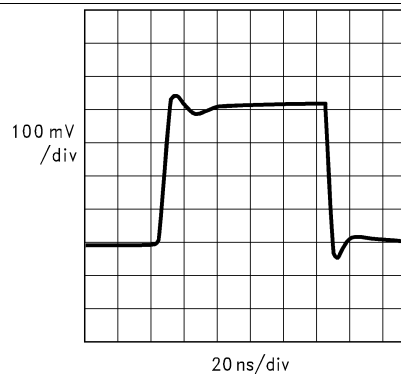


Figure 42. Small Signal Pulse Response,
 $A_V = -1$, $V_S = \pm 15$ V, $R_L = 100 \Omega$

Typical Characteristics (continued)

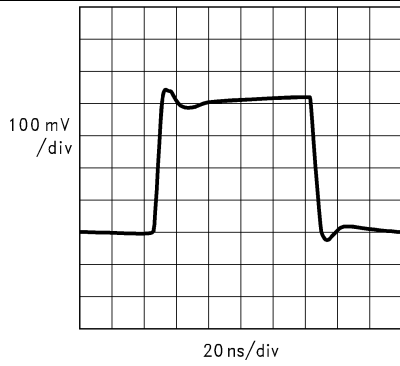


Figure 43. Small Signal Pulse Response,
 $A_V = -1$, $V_S = \pm 5$ V, $R_L = 100 \Omega$

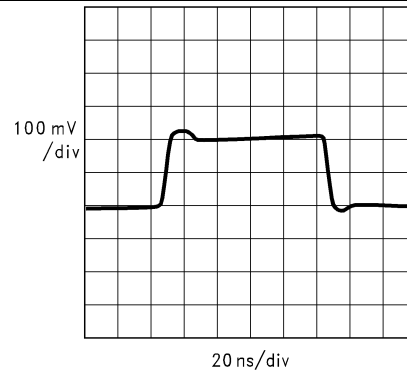


Figure 44. Small Signal Pulse Response,
 $A_V = -1$, $V_S = +5$ V, $R_L = 100 \Omega$

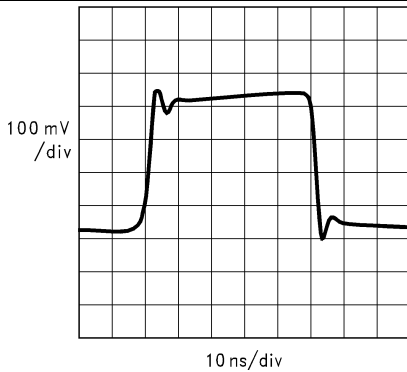


Figure 45. Small Signal Pulse Response,
 $A_V = +1$, $V_S = \pm 15$ V, $R_L = 100 \Omega$

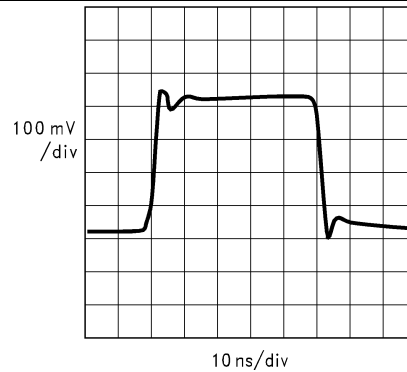


Figure 46. Small Signal Pulse Response,
 $A_V = +1$, $V_S = \pm 5$ V, $R_L = 100 \Omega$

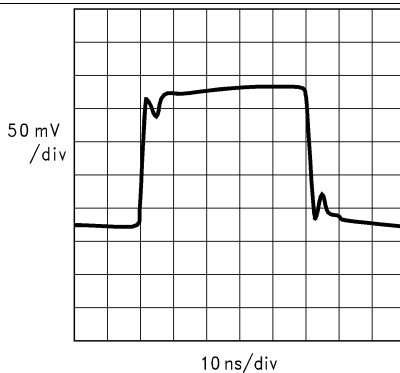


Figure 47. Small Signal Pulse Response,
 $A_V = +1$, $V_S = +5$ V, $R_L = 100 \Omega$

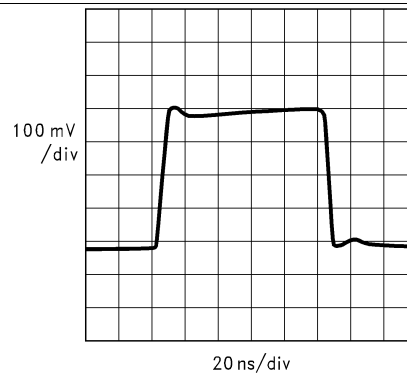


Figure 48. Small Signal Pulse Response,
 $A_V = +2$, $V_S = \pm 15$ V, $R_L = 100 \Omega$

Typical Characteristics (continued)

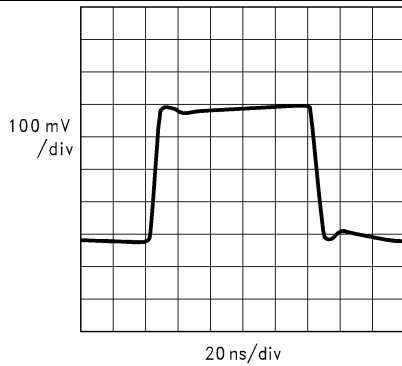


Figure 49. Small Signal Pulse Response, $A_V = +2$, $V_S = \pm 5$ V, $R_L = 100 \Omega$

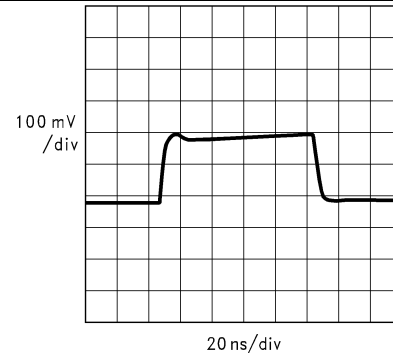


Figure 50. Small Signal Pulse Response, $A_V = +2$, $V_S = +5$ V, $R_L = 100 \Omega$

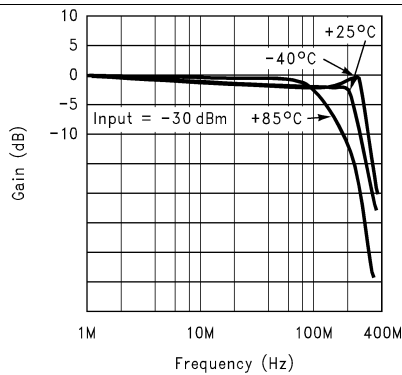


Figure 51. Closed Loop Frequency Response vs. Temperature, $V_S = \pm 15$ V, $A_V = +1$, $R_L = 100 \Omega$

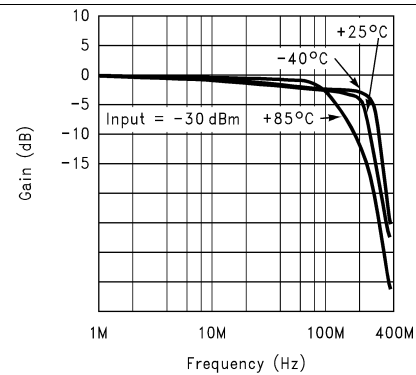


Figure 52. Closed Loop Frequency Response vs. Temperature, $V_S = \pm 5$ V, $A_V = +1$, $R_L = 100 \Omega$

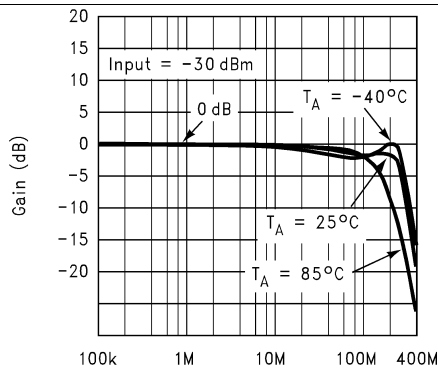


Figure 53. Closed Loop Frequency Response vs. Temperature, $V_S = +5$ V, $A_V = +1$, $R_L = 100 \Omega$

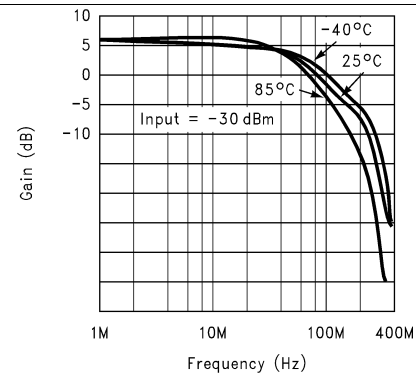


Figure 54. Closed Loop Frequency Response vs. Temperature, $V_S = \pm 15$ V, $A_V = +2$, $R_L = 100 \Omega$

Typical Characteristics (continued)

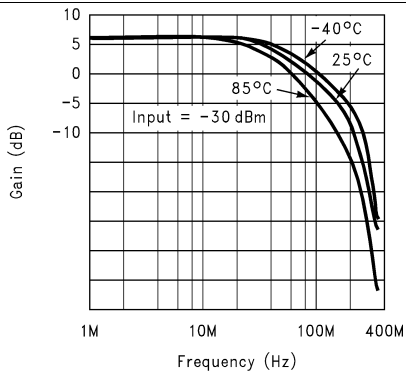


Figure 55. Closed Loop Frequency Response vs. Temperature,
 $V_S = \pm 5\text{ V}$, $A_V = +2$, $R_L = 100\ \Omega$

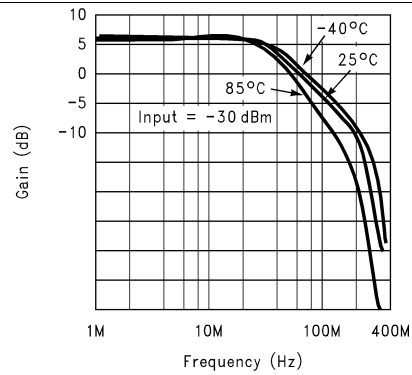


Figure 56. Closed Loop Frequency Response vs. Temperature,
 $V_S = +5\text{ V}$, $A_V = +2$, $R_L = 100\ \Omega$

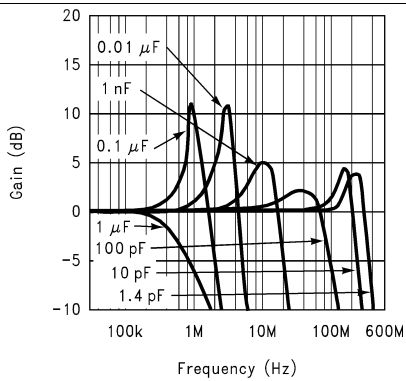


Figure 57. Closed Loop Frequency Response vs. Capacitance Load
 $(A_V = +1, V_S = \pm 15\text{ V})$

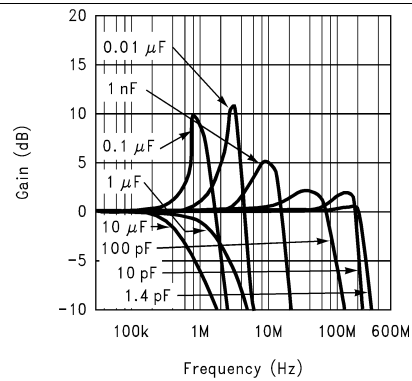


Figure 58. Closed Loop Frequency Response vs. Capacitive Load
 $(A_V = +1, V_S = \pm 5\text{ V})$

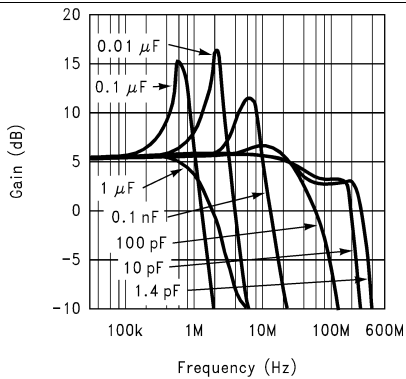


Figure 59. Closed Loop Frequency Response vs. Capacitive Load
 $(A_V = +2, V_S = \pm 15\text{ V})$

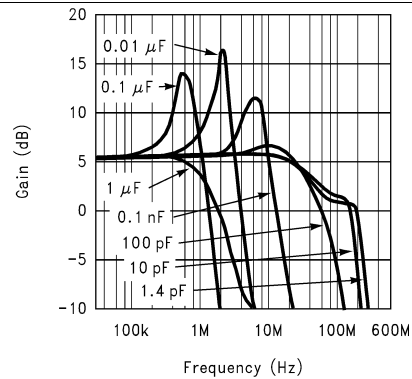


Figure 60. Closed Loop Frequency Response vs. Capacitive Load
 $(A_V = +2, V_S = \pm 5\text{ V})$

Typical Characteristics (continued)

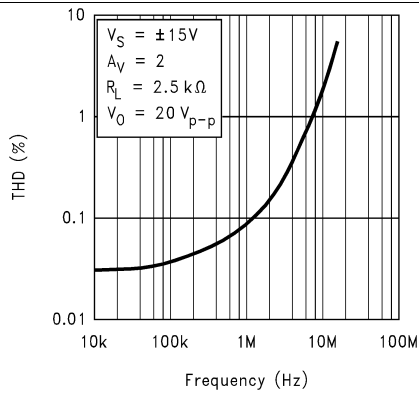


Figure 61. Total Harmonic Distortion vs. Frequency

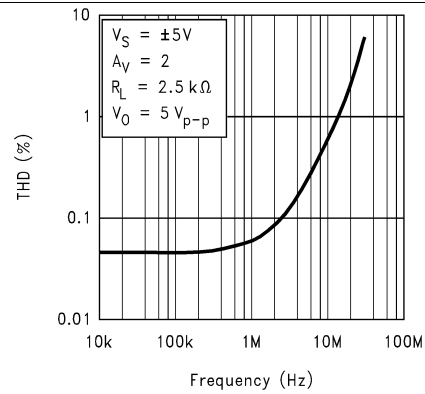


Figure 62. Total Harmonic Distortion vs. Frequency

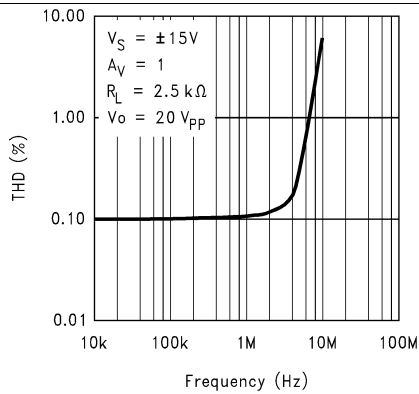


Figure 63. Total Harmonic Distortion vs. Frequency

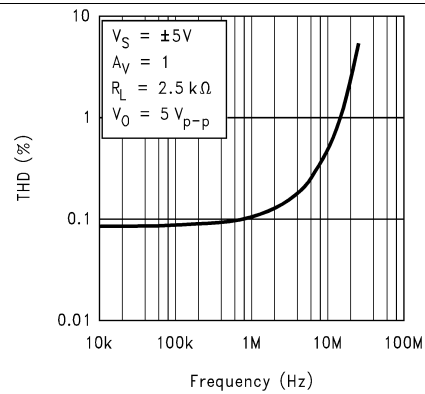


Figure 64. Total Harmonic Distortion vs. Frequency

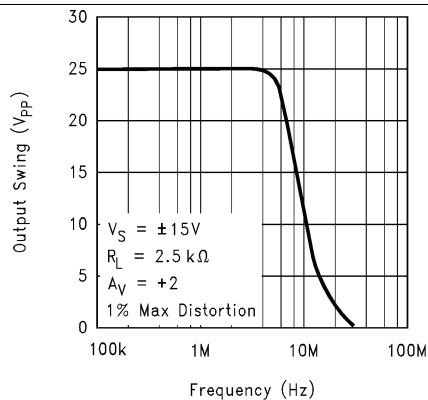


Figure 65. Undistorted Output Swing vs. Frequency

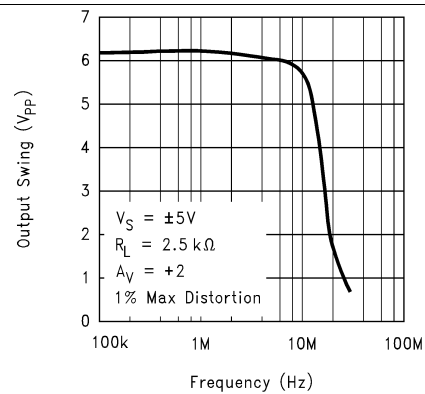
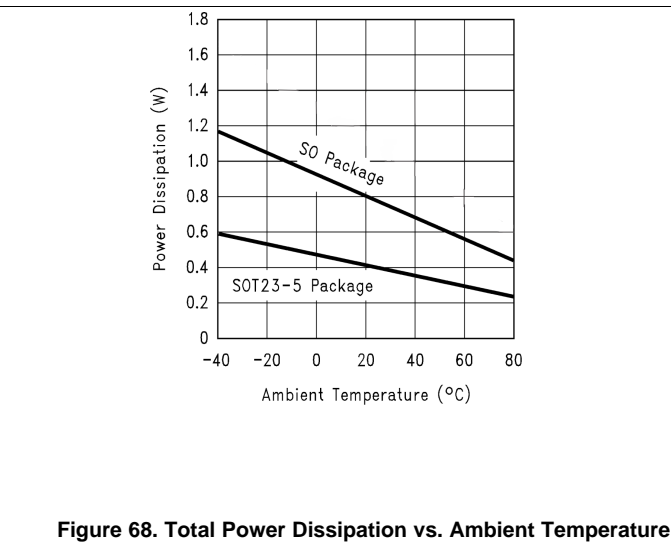
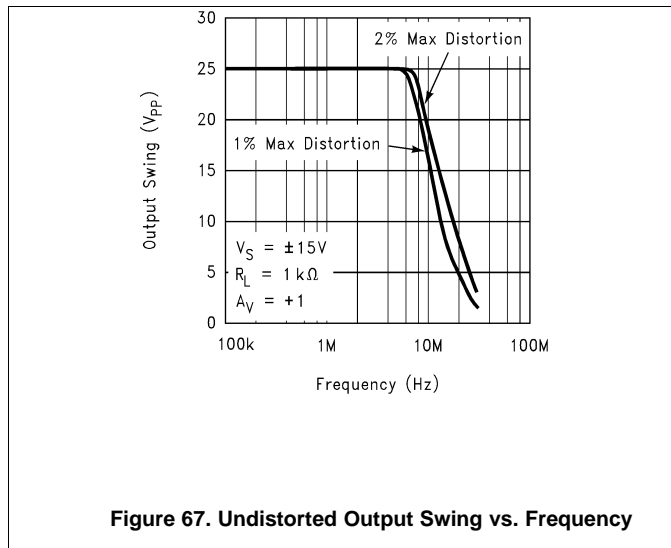


Figure 66. Undistorted Output Swing vs. Frequency

Typical Characteristics (continued)



7 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

7.1 Application Information

Table 1 depicts the maximum operating supply voltage for each package type

Table 1. Maximum Supply Voltage Values

	SOT-23	SO-8
Single Supply	10 V	30 V
Dual Supplies	±5 V	±15 V

Stable unity gain operation is possible with supply voltage of 5 V for all capacitive loads. This allows the possibility of using the device in portable applications with low supply voltages with minimum components around it.

Above a supply voltage of 6 V (±3 V Dual supplies), an additional resistor and capacitor (shown in [Figure 69](#)) should be placed in the feedback path to achieve stability at unity gain over the full temperature range.

The package power dissipation should be taken into account when operating at high ambient temperatures and/or high power dissipative conditions. Refer to the power derating curves in the data sheet for each type of package.

In determining maximum operable temperature of the device, make sure the total power dissipation of the device is considered; this includes the power dissipated in the device with a load connected to the output as well as the nominal dissipation of the op amp.

The device is capable of tolerating momentary short circuits from its output to ground but prolonged operation in this mode will damage the device, if the maximum allowed junction temperature is exceeded.

7.2 Typical Applications

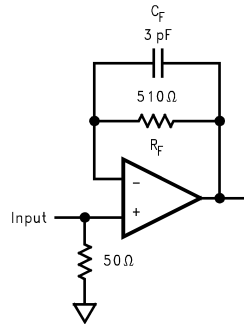


Figure 69. Typical Circuit for $A_V = +1$ Operation ($V_S = 6\text{ V}$)

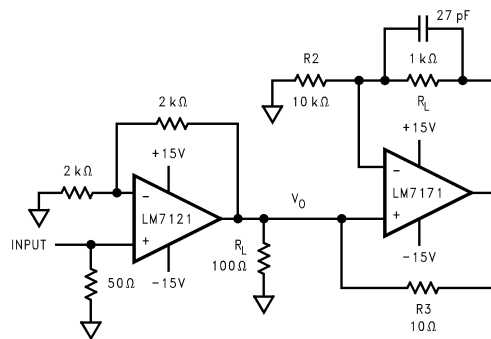


Figure 70. Simple Circuit to Improve Linearity and Output Drive Current

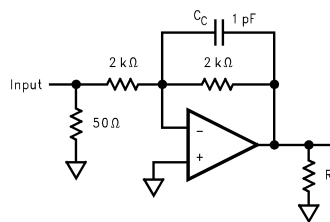
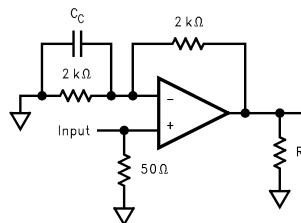


Figure 71. $A_V = -1$



$C_C = 2\text{ pF}$ for $R_L = 100\ \Omega$
 $C_C = \text{Open}$ for $R_L = \text{Open}$

Figure 72. $A_V = +2$

Typical Applications (continued)

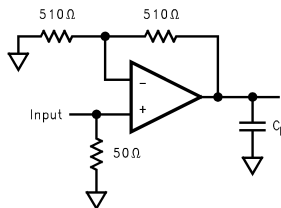
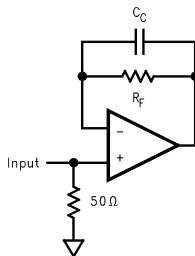
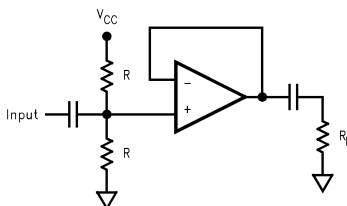


Figure 73. $A_V = +2$, Capacitive Load



$R_F = 0 \Omega$, $C_C = \text{Open}$ for $V_S < 6 \text{ V}$
 $R_F = 510 \Omega$, $C_C = 3 \text{ pF}$ for $V_S \geq 6 \text{ V}$

Figure 74. $A_V = +1$



$R_F = 0 \Omega$, $C_C = \text{Open}$ for $V_S < 6 \text{ V}$
 $R_F = 510 \Omega$, $C_C = 3 \text{ pF}$ for $V_S \geq 6 \text{ V}$

Figure 75. $A_V = +1$, $V_S = +5 \text{ V}$, Single Supply Operation

7.2.1 Design Requirements

7.2.1.1 Current Boost Circuit

The circuit in [Figure 70](#) can be used to achieve good linearity along with high output current capability.

By proper choice of R_3 , the LM7121 output can be set to supply a minimal amount of current, thereby improving its output linearity.

R_3 can be adjusted to allow for different loads:

$$R_3 = 0.1 R_L \quad (1)$$

[Figure 70](#) has been set for a load of 100Ω . Reasonable speeds ($< 30 \text{ ns}$ rise and fall times) can be expected up to 120 mA of load current (see [Figure 77](#) for step response across the load).

Typical Applications (continued)

7.2.2 Detailed Design Procedure

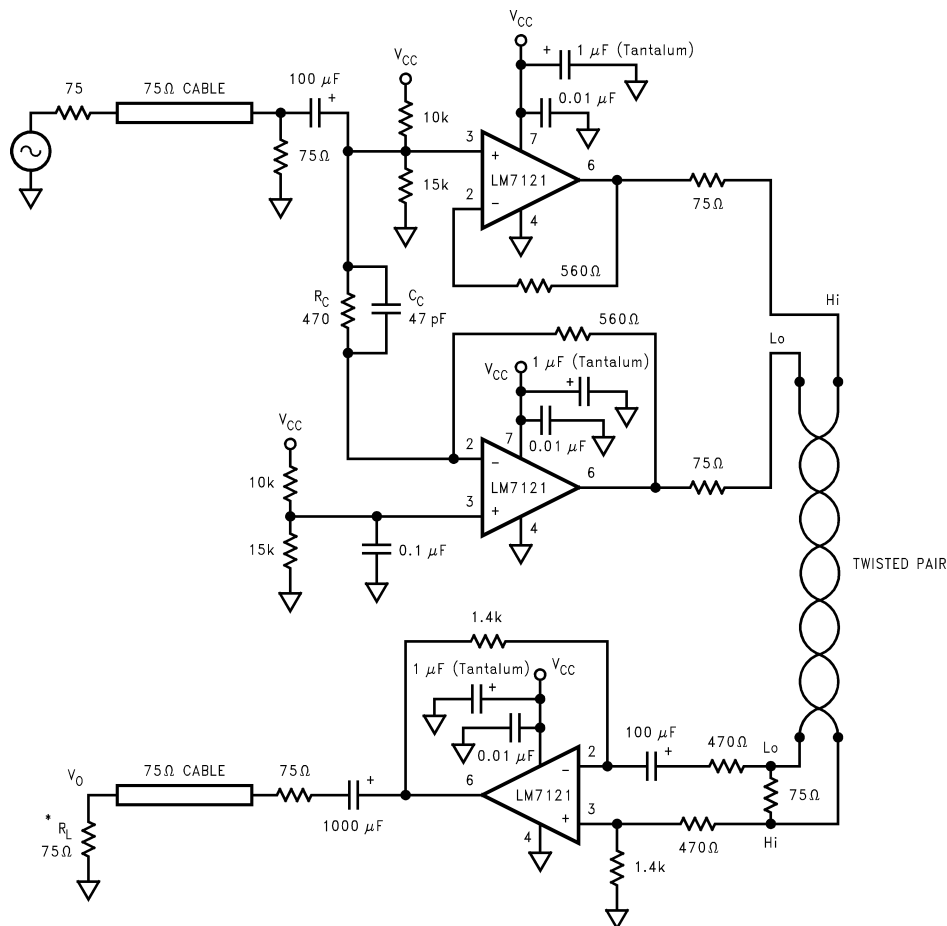
It is very important to keep the lead lengths to a minimum and to provide a low impedance current path by using a ground-plane on the board.

CAUTION

If R_L is removed, the current balance at the output of LM7121 would be disturbed and it would have to supply the full amount of load current. This might damage the part if power dissipation limit is exceeded.

7.2.2.1 Color Video on Twisted Pairs Using Single Supply

The circuit shown in Figure 76 can be used to drive in excess of 25 meters length of twisted pair cable with no loss of resolution or picture definition when driving a NTSC monitor at the load end.



Pin numbers shown are for SO-8 package.

* Input termination of NTSC monitor.

Figure 76. Single Supply Differential Twisted Pair Cable Transmitter/Receiver, $8.5\text{ V} \leq V_{CC} \leq 30\text{ V}$

Typical Applications (continued)

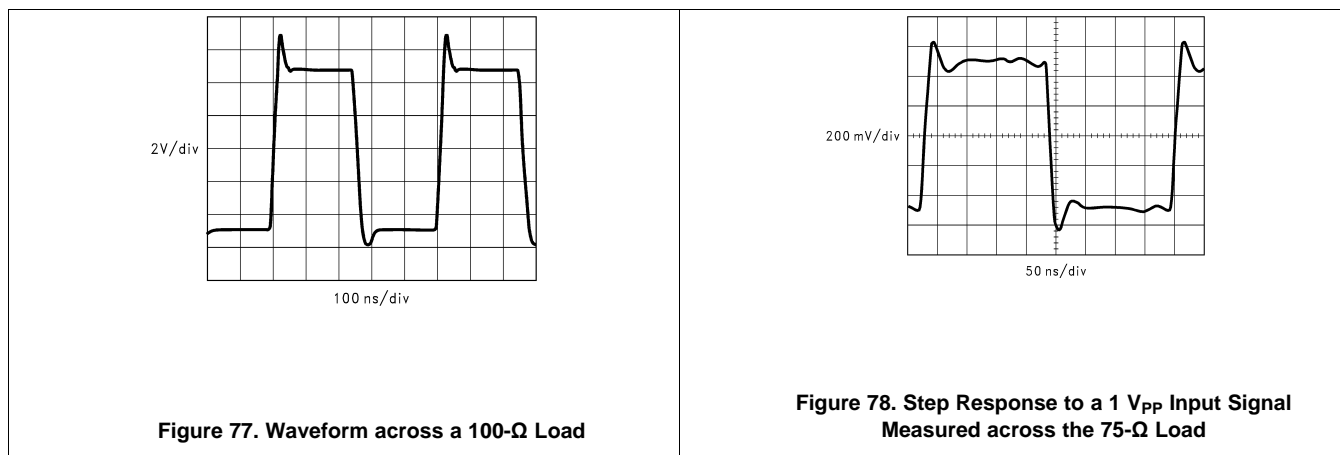
Differential Gain and Differential Phase errors measured at the load are less than 1% and 1° respectively

R_G and C_C can be adjusted for various cable lengths to compensate for the line losses and for proper response at the output. Values shown correspond to a twisted pair cable length of 25 meters with about 3 turns/inch (see [Figure 78](#) for step response).

The supply voltage can vary from 8.5 V up to 30 V with the output rise and fall times under 12 ns. With the component values shown, the overall gain from the input to the output is about 1.

Even though the transmission line is not terminated in its nominal characteristic impedance of about 600 Ω, the resulting reflection at the load is only about 5% of the total signal and in most cases can be neglected. Using 75 termination instead, has the advantage of operating at a low impedance and results in a higher realizable bandwidth and signal fidelity.

7.2.3 Application Performance Plots



8 Device and Documentation Support

8.1 Trademarks

All trademarks are the property of their respective owners.

8.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

8.3 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM7121IM	NRND	SOIC	D	8	95	TBD	Call TI	Call TI	-40 to 85	LM71 21IM	
LM7121IM/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LM71 21IM	Samples
LM7121IM5	NRND	SOT-23	DBV	5	1000	TBD	Call TI	Call TI	-40 to 85	A03A	
LM7121IM5/NOPB	ACTIVE	SOT-23	DBV	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	A03A	Samples
LM7121IM5X/NOPB	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	A03A	Samples
LM7121IMX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LM71 21IM	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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